



# Large Size Yttrium Doped BaF<sub>2</sub> Crystals for the Mu2e-II Experiment

Chen Hu<sup>1</sup>, Liyuan Zhang<sup>1</sup>, Ren-Yuan Zhu<sup>1</sup>, Junfeng Chen<sup>2</sup>, Dong Wang<sup>2</sup>, Jianqiang Liu<sup>3</sup>, Mingrong Zhang<sup>3</sup>

<sup>1</sup>California Institute of Technology

<sup>2</sup>Shanghai Institute of Ceramics

<sup>3</sup>Beijing Glass Research Institute

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### Introduction



- The Mu2e-I experiment is building a undoped CsI calorimeter, which has a fast scintillation at 310 nm with 30 ns decay time and survives an ionization dose up to 100 krad. A radiation level beyond 100 krad is expected by Mu2e-II, where CsI will be blackened.
- BaF<sub>2</sub> crystal is featured with a ultrafast scintillation at 220 nm with 0.5 ns decay time and an adequate radiation hardness. Its slow scintillation at 300 nm with 650 ns decay time, however, would cause pileup in a high rate environment.
- Two approaches are used to suppress the slow scintillation in BaF<sub>2</sub>: selective RE doping and/or dedicated photodetector. Yttrium doping in BaF<sub>2</sub> crystals is found effective, promising a ultrafast calorimeter for Mu2e-II.
- Mass production capability of BaF<sub>2</sub> exists in industry:
  - BGRI (China), Incrom (Russia) and SICCAS (China);
  - Hellma (Germany).
- Recent progress in large size BaF<sub>2</sub>:Y crystals for Mu2e-II is reported.



# Some Fast Inorganic Scintillators



	LSO/LYSO	GSO	YSO	CsI	BaF <sub>2</sub>	CeF₃	CeBr <sub>3</sub>	LaCl₃	LaBr <sub>3</sub>	Plastic scintillator (BC 404) <sup>①</sup>
Density (g/cm³)	7.4	6.71	4.44	4.51	4.89	6.16	5.23	3.86	5.29	1.03
Melting point (°C)	2050	1950	1980	621	1280	1460	722	858	783	<b>70</b> <sup>#</sup>
Radiation Length (cm)	1.14	1.38	3.11	1.86	2.03	1.7	1.96	2.81	1.88	42.54
Molière Radius (cm)	2.07	2.23	2.93	3.57	3.1	2.41	2.97	3.71	2.85	9.59
Interaction Length (cm)	20.9	22.2	27.9	39.3	30.7	23.2	31.5	37.6	30.4	78.8
Z value	64.8	57.9	33.3	54	51.6	50.8	45.6	47.3	45.6	5.82
dE/dX (MeV/cm)	9.55	8.88	6.56	5.56	6.52	8.42	6.65	5.27	6.9	2.02
Emission Peak <sup>a</sup> (nm)	420	430	420	310	300 220	340 300	371	335	356	408
Refractive Index <sup>b</sup>	1.82	1.85	1.8	1.95	1.5	1.62	1.9	1.9	1.9	1.58
Relative Light Yield <sup>a,c</sup>	100	45	76	3.6 1.1	42 4.1	8.6	99	15 49	153	35
Decay Time <sup>a</sup> (ns)	40	73	60	30	650 0.5	30	17	570 24	20	1.8
d(LY)/dT <sup>d</sup> (%/°C)	-0.2	-0.4	-0.1	-1.4	-1.9 0.1	~0	-0.1	0.1	0.2	~0

a. Top line: slow component, bottom line: fast component.

http://pdg.lbl.gov/2008/AtomicNuclearProperties/HTML\_PAGES/216.html

The 0.5 ns scintillation in BaF<sub>2</sub> promises a ultrafast crystal calorimeter to face the challenge of high event rate expected by Mu2e-II

b. At the wavelength of the emission maximum.

c. Relative light yield normalized to the light yield of LSO

d. At room temperature (20°C)

<sup>#.</sup> Softening point

<sup>1.</sup> http://www.detectors.saint-gobain.com/Plastic-Scintillator.aspx

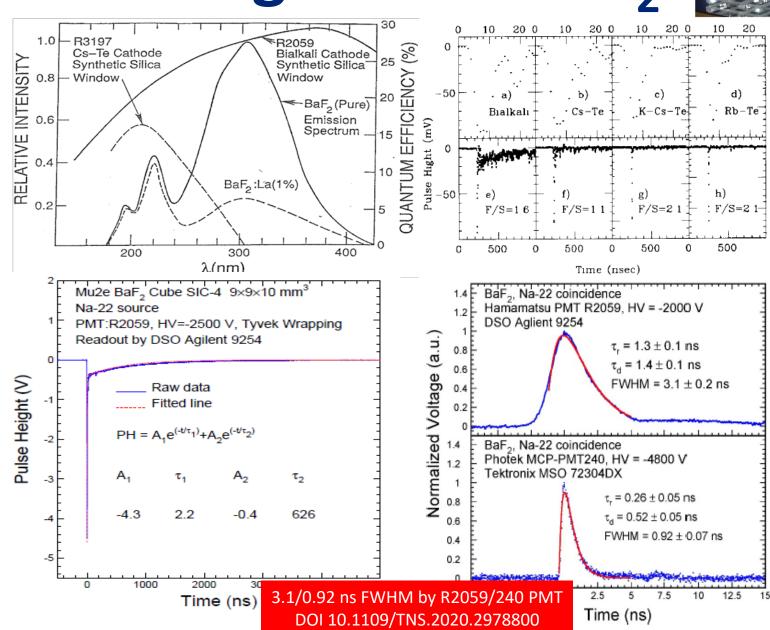


# **Ultrafast and Slow Light from BaF<sub>2</sub>**



BaF<sub>2</sub> has a ultrafast scintillation component @ 220 nm with 0.5 ns decay time and an intensity a little less than undoped Csl. It has also a factor of 5 larger slow component @ 300 nm with 300 ns decay time.

Slow suppression may be achieved by selective rare earth doping, e.g. Y, La and Ce, in BaF<sub>2</sub>, and/or photodetectors with filters or a solar- blind cathode, e.g. Cs-Te, K-Cs-Te and Rb-Te. NIMA 340 (1994) 442-457



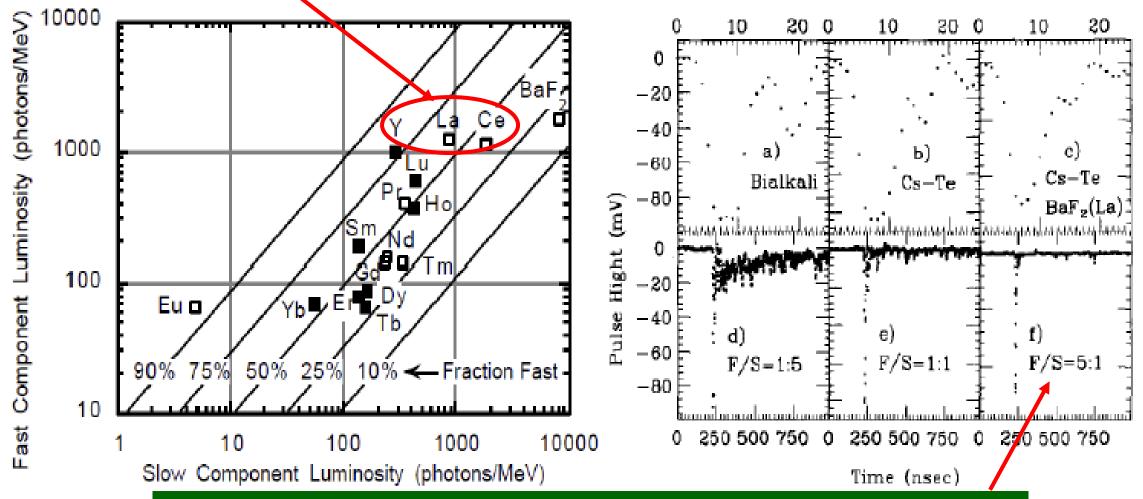


## **Slow Suppression: Doping & Readout**



Slow suppression by RE doped BaF<sub>2</sub> powders: Y, La and Ce (1994)

B.P. SOBOLEV et al., "SNPPRESSION OF BaF2 SLOW COMPONENT OF X-RAY LUMINESCENCE IN NON-STOICHIOMETRIC Ba0.9R0.1F2 CRYSTALS (R=RARE EARTH N EMENT)," Proceedings of The Material Research Society: Scintillator and Phosphor Materials, pp. 277-283, 1994.



Cs-Te cathode plus La doping raises F/S from 1/5 to 5/1, NIMB 91 (1991) 61-66

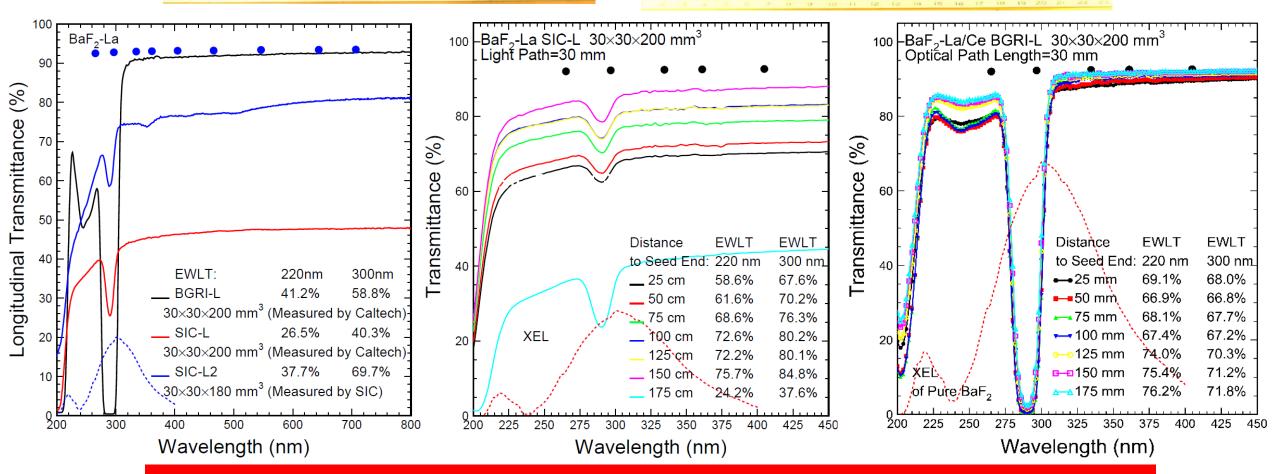


## Transmittance of BaF<sub>2</sub>:La and BaF<sub>2</sub>:La/Ce



BGRI BaF<sub>2</sub>:La/Ce 30 x 30 x 200 mm<sup>3</sup>

SIC BaF<sub>2</sub>:La 30 x 30 x 200 mm<sup>3</sup>



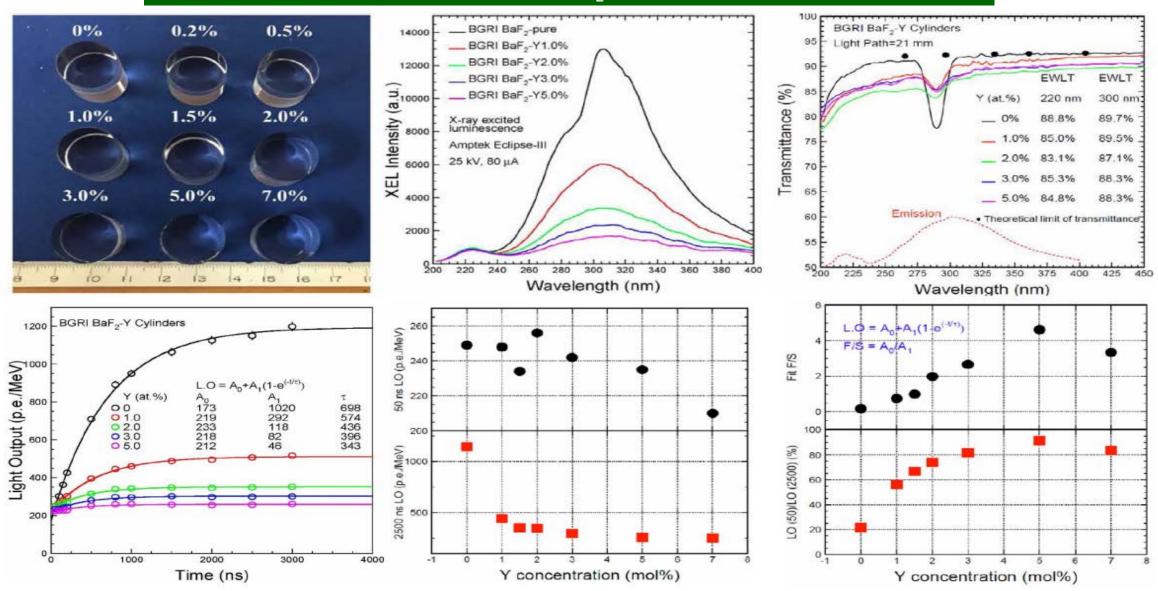
Absorptions observed in La and La/Ce doped BaF<sub>2</sub>, published in IEEE TNS 66 (2019) 506-518



# Yttrium Doped Small BaF<sub>2</sub> Samples



Increased F/S ratio observed in BGRI BaF<sub>2</sub>:Y crystals, Proc. SPIE 10392 (2017)

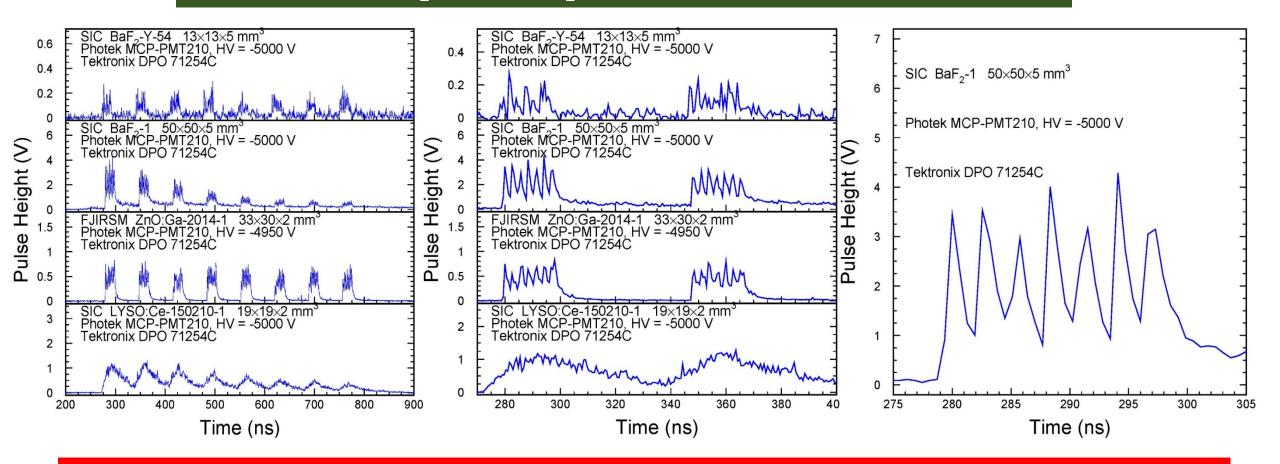




#### APS Beam Test: BaF<sub>2</sub>:Y, BaF<sub>2</sub>, ZnO:Ga & LYSO



X-ray bunches with 2.83 ns spacing in septuplet are clearly resolved by ultrafast BaF<sub>2</sub>:Y and BaF<sub>2</sub> crystals, NIMA 240 (2019) 223-239



Amplitude reduction in BaF<sub>2</sub> and LYSO due to space charge in PMT from slow scintillation, but not in BaF<sub>2</sub>:Y

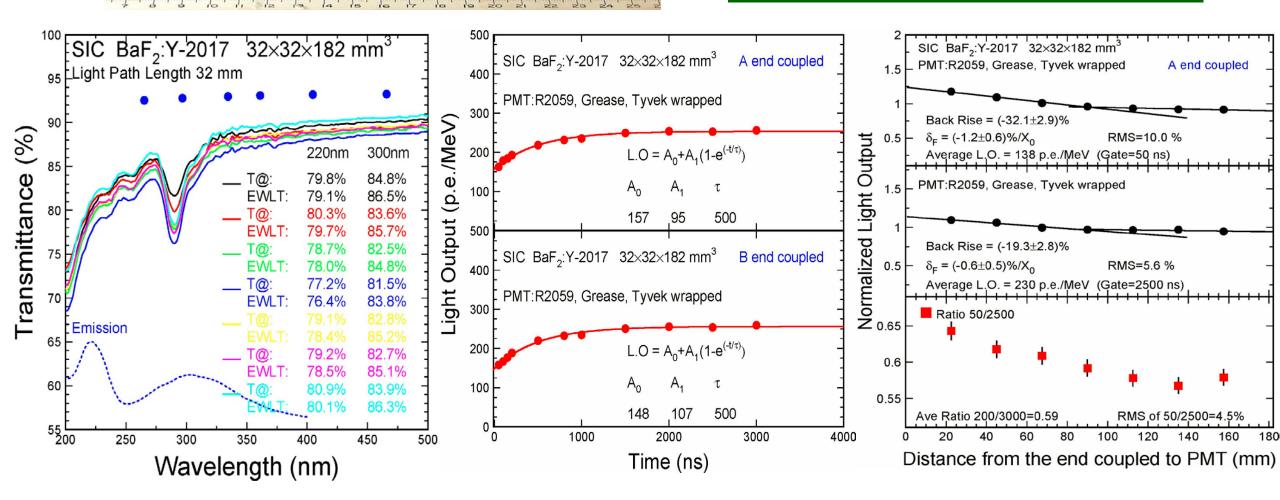


## SIC BaF<sub>2</sub>:Y-2017



SIC BaF<sub>2</sub>:Y-2017 32 x 32 x 182 mm<sup>3</sup>

F: 150 p.e./MeV, F/S: 1.5 F/T LRU: 10%/6%,  $\delta_F$ :-1.2%/X<sub>0</sub>



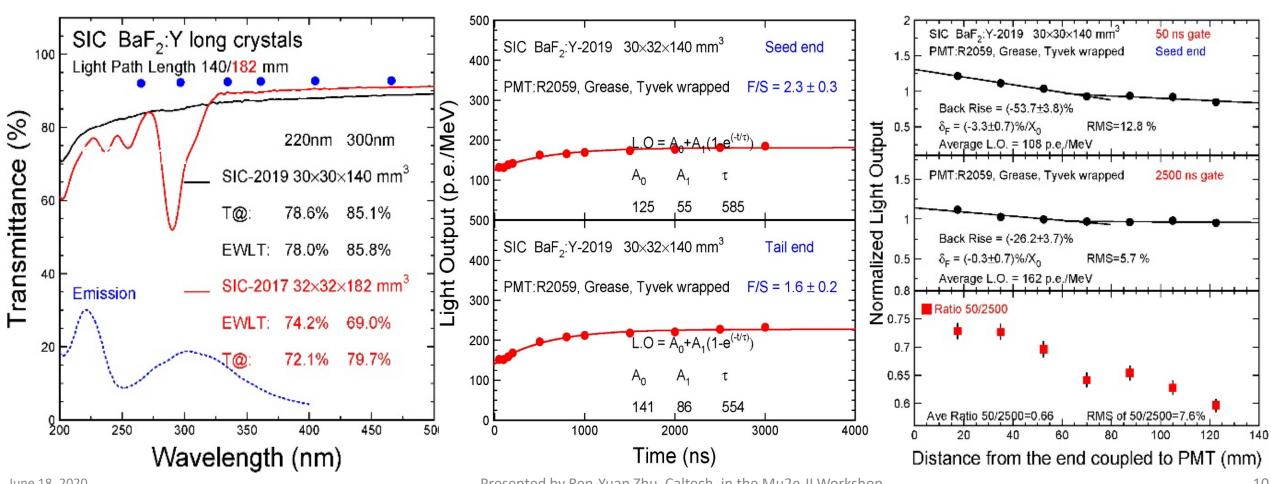


# SIC BaF<sub>2</sub>:Y-2019





F: 130 p.e./MeV, F/S: 2  $F/T LRU: 13\%/6\% \%, \delta_{F}:-3.3\%/X_{0}$ 



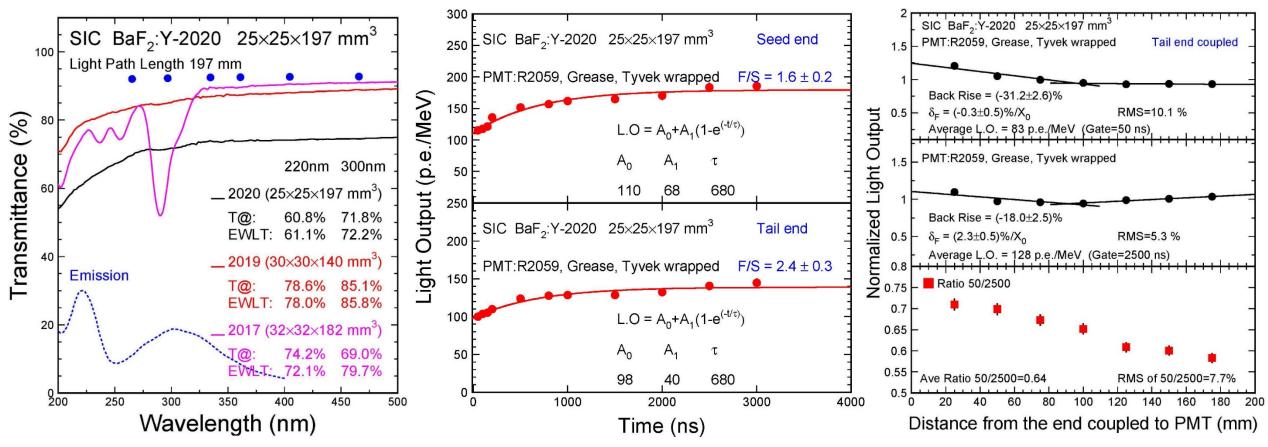


# SIC BaF<sub>2</sub>:Y-2020





F: 100 p.e./MeV, F/S: 2 F/T LRU: 10%/5% %,  $\delta_F$ :-0.3%/X<sub>0</sub>

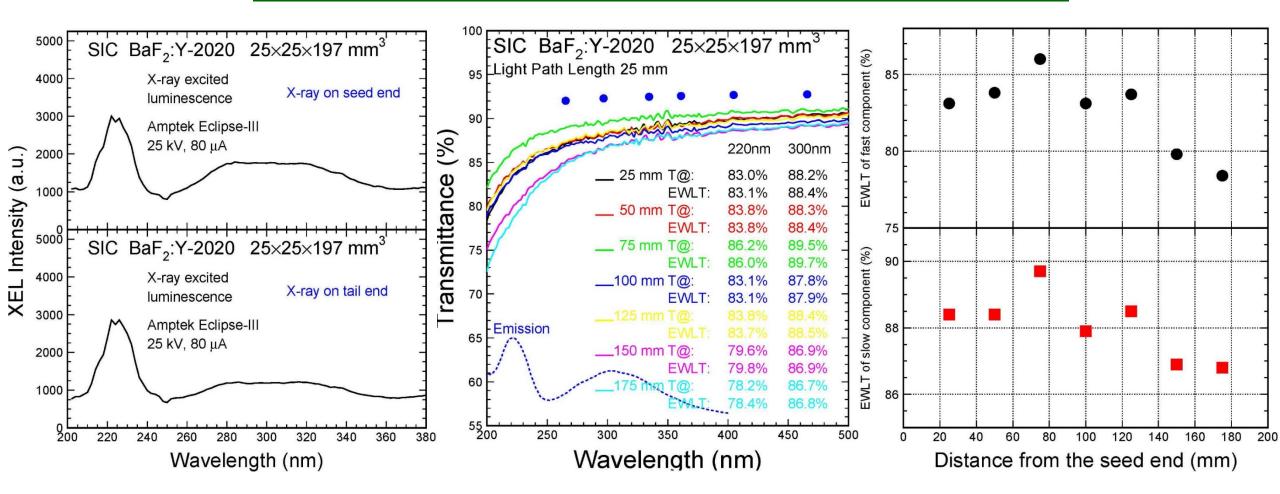




# SIC BaF<sub>2</sub>:Y-2020: Transverse T



A variation of slow emission intensity and more scattering centers starting from 15 cm from the seed





# Summary: SIC BaF<sub>2</sub>:Y Long Crystals

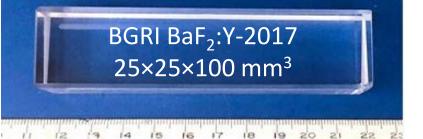


ID	Dimension (mm³)	EWLT Fast (%)	EWLT Slow (%)	Coupling end	<sup>22</sup> Na/α	Light Response Uniformity						
					50 ns LO (p.e./MeV)	2500 ns LO (p.e./MeV)	LO(50) /LO(2500)	F	F/S	50 ns LO	2500 ns LO	LO(50)/ LO(2500)
SIC BaF <sub>2</sub> :Y- 32 2017	20, 20, 400	72.1	79.7	Α	162	253	0.64	157	1.7	138 (10.0%)	230 (5.6%)	0.59 (4.5%)
	32×32×182			В	158	254	0.62	148	1.4	116 (19.1%)	200 (16.4%)	0.57 (3.7%)
SIC BaF <sub>2</sub> :Y- 30×30× 2019	2020140	78.0 85.8	Α	132	181	0.73	125	2.3	108 (12.8%)	162 (5.7%)	0.66 (7.6%)	
	30×30×140		8.69	В	152	227	0.67	141	1.6	117 (15.6%)	177 (14.9%)	0.66 (1.5%)
SIC BaF <sub>2</sub> :Y- 2020	2525107	61.1	72.2	Seed	115	183	0.63	110	1.6	88 (17.7%)	136 (20.5%)	0.64 (2.8%)
	25×25×197			Tail	100	141	0.71	98	2.4	83 (10.1%)	128 (5.3%)	0.64 (7.7%)

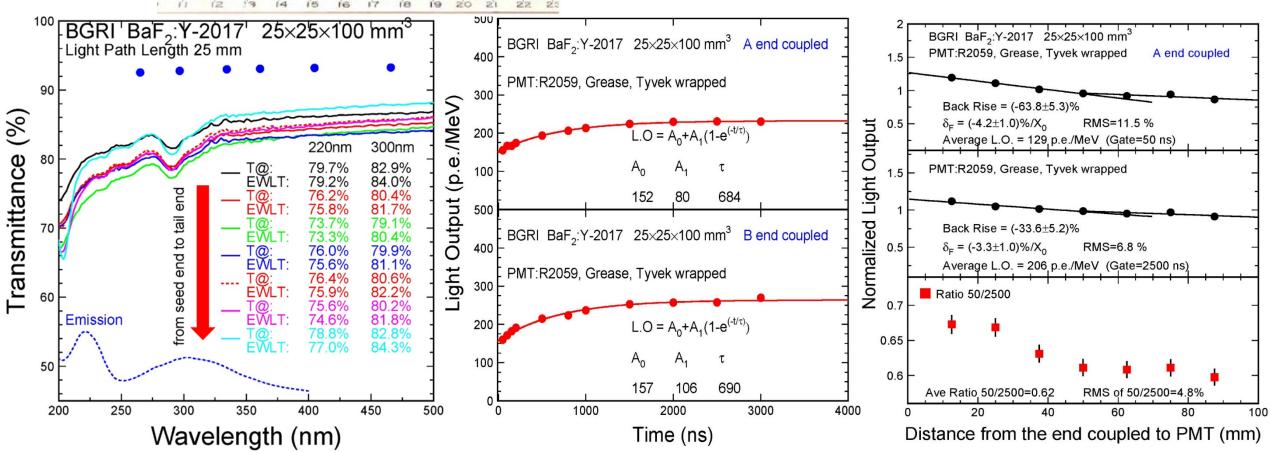


# **BGRI BaF<sub>2</sub>:Y-2017**





F: 150 p.e./MeV, F/S: 1.5 F/T LRU: 12%/7% %, δ<sub>F</sub>:-4.2%/X<sub>0</sub>



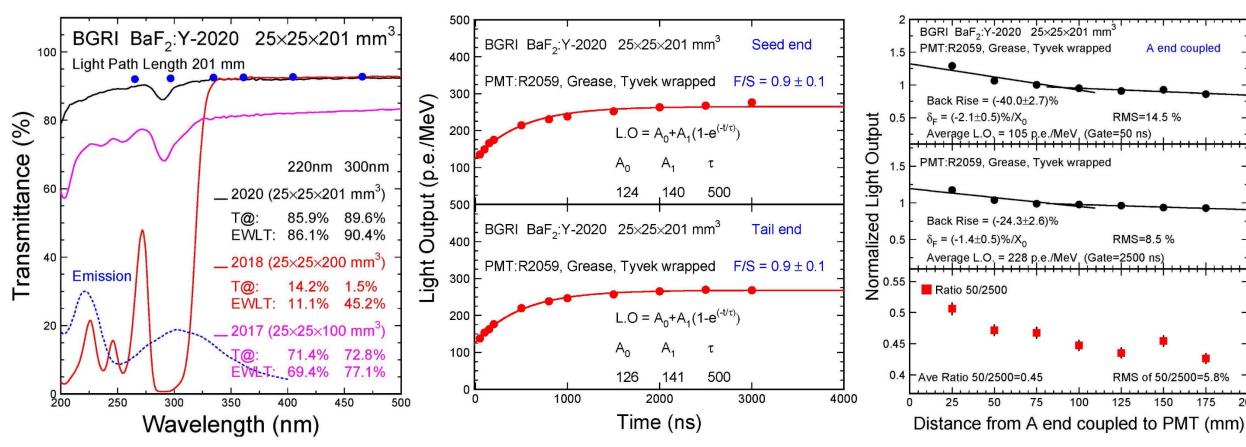


# **BGRI BaF<sub>2</sub>:Y-2020**



BGRI BaF<sub>2</sub>:Y-2020, 25 x 25 x 201 mm<sup>3</sup>

F: 125 p.e./MeV, F/S: 0.9 F/T LRU: 15%/9% %,  $\delta_F$ :-2.1%/X<sub>0</sub>

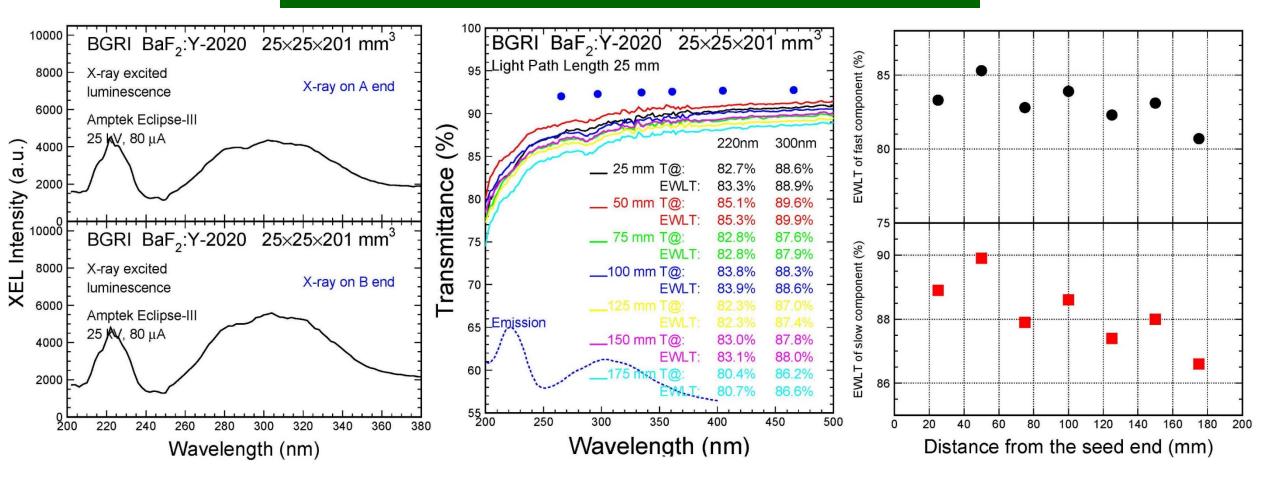




# BGRI BaF<sub>2</sub>:Y-2020: Transverse T



A variation of slow emission intensity and good optical quality along the crystal length





# Summary: BGRI BaF<sub>2</sub>:Y Long Crystals



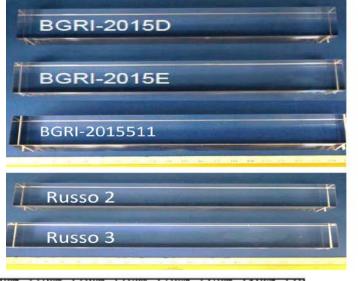
ID	Dimension (mm³)	EWLT Fast (%)	EWLT Slow (%)	Coupling end	So	Light Response Uniformity										
					50 ns LO (p.e./MeV)	2500 ns LO (p.e./MeV)	LO(50) /LO(2500)	F	F/S	50 ns LO	2500 ns LO	LO(50)/ LO(2500)				
BGRI BaF <sub>2</sub> :Y-		69.4	60.4	60.4	60.4	60.4	77 1	Α	155	231	0.67	152	1.9	129 (11.5%)	206 (6.8%)	0.62 (4.8%)
2017	25×25×100		77.1	В	160	258	0.62	157	1.5	129 (15.4%)	214 (13.7%)	0.60 (2.1%)				
BGRI BaE . V		11.1	.1 45.2	A	133	317	0.42	203*	NA	83 (30.6%)	229 (20.4%)	0.35 (9.4%)				
BaF <sub>2</sub> :Y- 25× 2018	25×25×200			В	133	265	0.52	159*	NA	89 (26.4%)	228 (8.7%)	0.38 (17.2%)				
BGRI BaF <sub>2</sub> :Y- 2020	25×25×201	61.1	72.2	A	135	268	0.50	124	0.9	105 (14.5%)	228 (8.5%)	0.45 (5.8%)				
				В	138	270	0.51	126	0.9	106 (17.1%)	221 (14.7%)	0.47 (3.1%)				

<sup>\*</sup>Only one component with 30~50 ns decay time is observed, but no ultrafast component



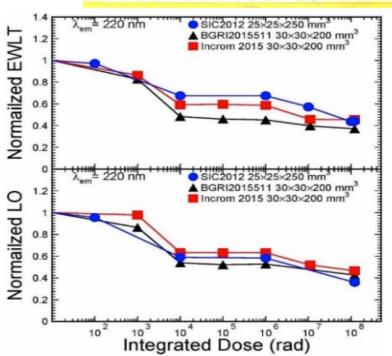
# **y-Ray Induced Damage in Large BaF**<sub>2</sub>

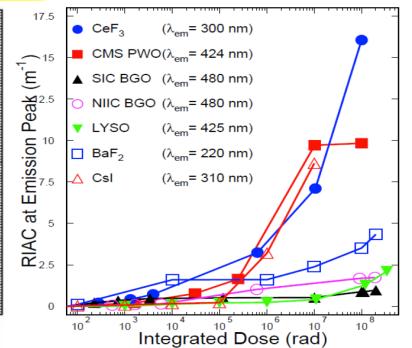


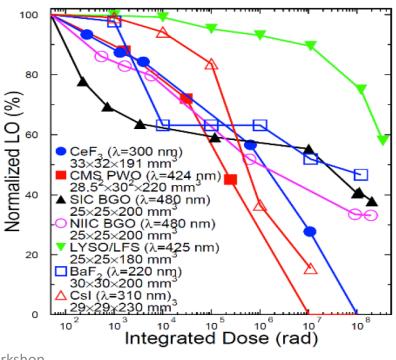




BaF<sub>2</sub> shows saturated damage from 10 krad to 100 Mrad, indicating good radiation resistance against γrays, IEEE TNS 63 (2016) 612-619



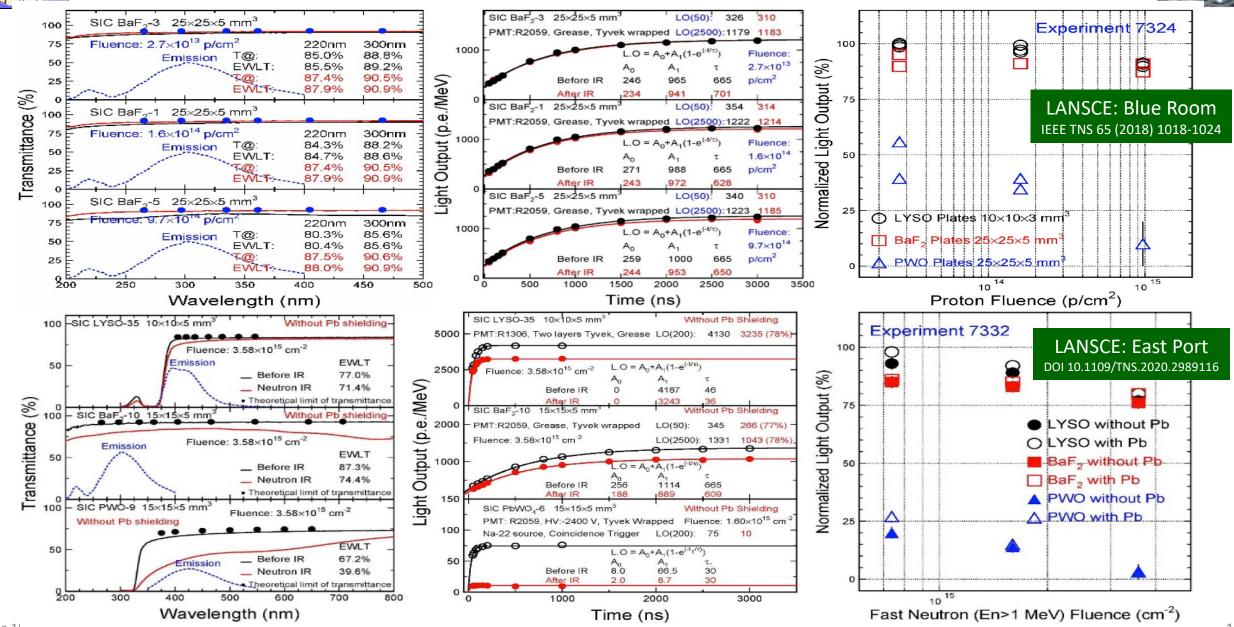




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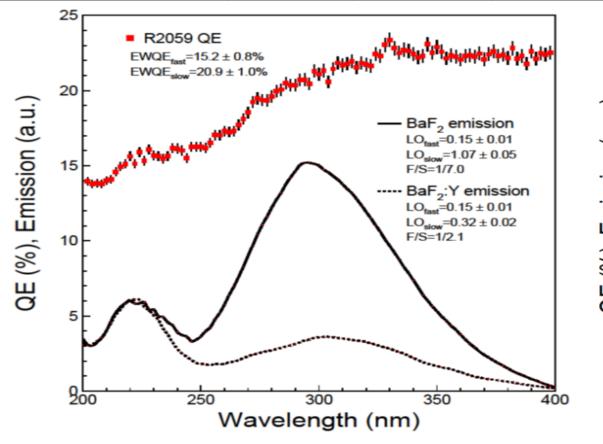


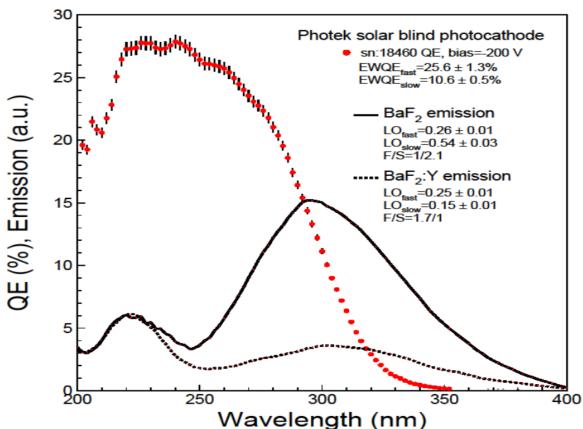


## **VUV PMT for BaF<sub>2</sub> and BaF<sub>2</sub>:Y**



Photo-detectors	EWQE <sub>fast</sub> (%)	EWQE <sub>slow</sub> (%)	BaF <sub>2</sub> LO <sub>fast</sub>	BaF <sub>2</sub> LO <sub>slow</sub>	BaF <sub>2</sub> F/S	BaF <sub>2</sub> :Y LO <sub>fast</sub>	BaF <sub>2</sub> :Y LO <sub>slow</sub>	BaF <sub>2</sub> :Y F/S
Hamamatsu R2059	15.2	20.9	0.15	1.07	1/7.0	0.15	0.32	1/2.1
Photek solar blind PMT	25.6	10.6	0.26	0.54	1/2.1	0.25	0.15	1/0.6



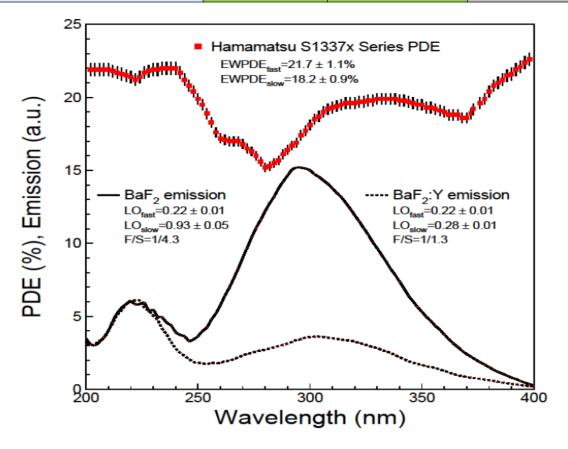


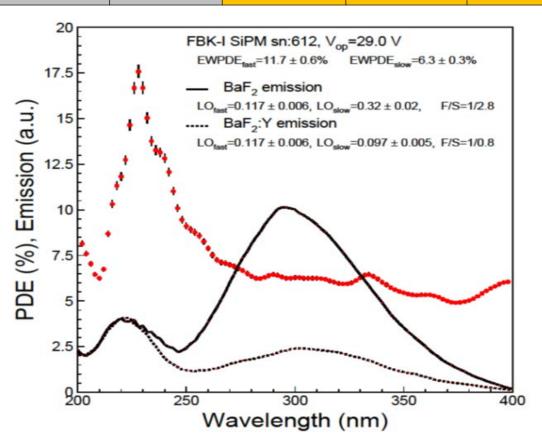


### **VUV SiPM for BaF<sub>2</sub> and BaF<sub>2</sub>:Y**



Photo-detectors	EWQE <sub>fast</sub> (%)	EWQE <sub>slow</sub> (%)	BaF <sub>2</sub> LO <sub>fast</sub>	BaF <sub>2</sub> LO <sub>slow</sub>	BaF₂ F/S	BaF <sub>2</sub> :Y LO <sub>fast</sub>	BaF <sub>2</sub> :Y LO <sub>slow</sub>	BaF <sub>2</sub> :Y F/S	
Hamamatsu s1337x	21.7	18.2	0.22	0.93	1/4.3	0.22	0.28	1/1.3	
FBK-I SiPM	11.7	6.3	0.12	0.32	1/2.8	0.12	0.097	1/0.8	







## Summary



- ☐ Undoped BaF<sub>2</sub> crystals provide adequate ultrafast light with 0.5 ns decay time. Yttrium doping increases its F/S ratio while maintaining the ultrafast intensity. With sub-ns pulse width BaF<sub>2</sub>:Y promises an ultrafast calorimeter for Mu2e-II.
- $\square$  20 cm long BaF<sub>2</sub> crystals are rad hard up to 120 Mrad against ionization dose. 5 mm thick BaF<sub>2</sub> plates irradiation at LANSCE by 800 MeV protons up to 1 x 10<sup>15</sup> p/cm<sup>2</sup> and fast neutrons up to 3.6 x 10<sup>15</sup> n<sub>eq</sub>/cm<sup>2</sup> did not cause significant light output loss, indicating BaF2 may be used in a severe radiation environment.
- $\square$  20 cm long BaF<sub>2</sub>:Y may reach LO<sub>F</sub>>100 p.e./MeV, F/S>2, 10% LRU and  $|\delta_F|$ <3%/X<sub>0</sub>. R&D will continue to optimize yttrium doping in large size BaF<sub>2</sub>:Y crystals for Mu2e-II.
  - ☐ SIC plans to reduce scattering centers by refining growth parameters;
  - ☐ BGRI plans to eliminate residual cerium contamination by purifying raw material.
  - $\square$  Caltech plans to investigate radiation hardness of BaF<sub>2</sub>:Y crystals.
- ☐ Effort is also needed to develop VUV photodetector, such as solar-blind SiPM, LAPPD or diamond-based photodetectors.

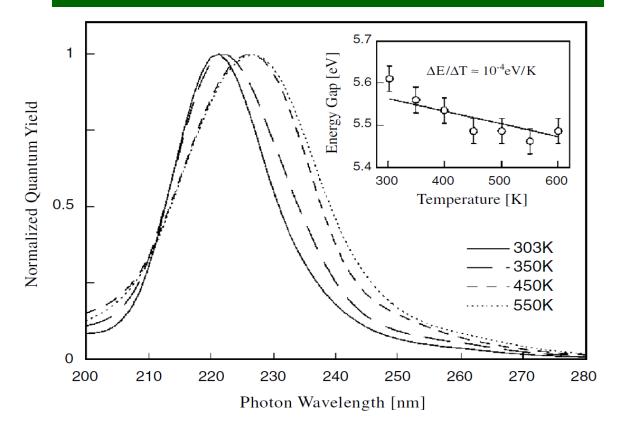
Acknowledgements: DOE HEP Award DE-SC001192



### **Diamond Photodetector**

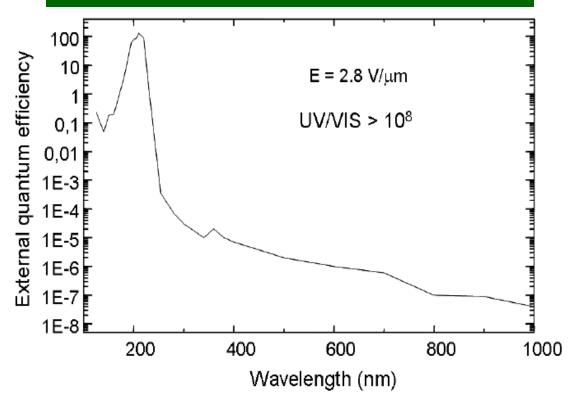


E. Monroy, F. Omnes and F. Calle,"Wide-bandgap semiconductor ultraviolet photodetectors, IOPscience 2003 Semicond. Sci. Technol. 18 R33



**Figure 6.** Quantum efficiency of diamond photoconductors at different temperatures and Arrhenius plot of the peak value (inset). (From [Sal00].)

E. Pace and A. De Sio, "Innovative diamond photo-detectors for UV astrophysics", Mem. S.A.It. Suppl. Vol. 14, 84 (2010)



**Fig. 4.** External quantum efficiency extended to visible and near infrared wavelength regions. The